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ON Semiconductor®

FDD3672-F085

N-Channel UltraFET Trench MOSFET

100V, 44A, 28mΩ

Features

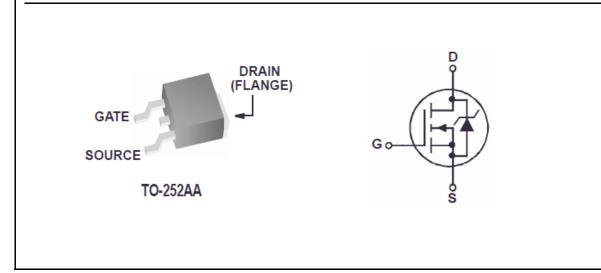
- Typ $r_{DS(on)}$ = 24m Ω at V_{GS} = 10V, I_D = 44A
- Typ Q_{g(10)} = 24nC at V_{GS} = 10V
- Low Miller Charge
- Low Q_{rr} Body Diode
- Optimized efficiency at high frequencies
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant

Applications

- DC/DC converters and Off-Line UPS
- Distributed Power Architectures and VRMs
- Primary Switch for 24V and 48V Systems
- High Voltage Synchronous Rectifier



ROHS



MOSFET Maximum Ratings $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain to Source Voltage		100	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current Continuous (T _C < 30°C, V _{GS} = 10V)		44	Α
D	Pulsed		See Figure 4	- A
E _{AS}	Single Pulse Avalanche Energy (N	lote 1)	73	mJ
Р	Power Dissipation		144	W
PD	Derate above 25°C		0.96	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to +175	°C

Thermal Characteristics

R_{\thetaJC}	Maximum Thermal Resistance Junction to Case	1.04	°C/W
R_{\thetaJA}	Maximum Thermal Resistance Junction to Ambient TO-263,1in ² copper pad area	52	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD3672	FDD3672-F085	TO-252AA	330mm	16mm	2500 units

Electrical Characteristics T_J = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					

B _{VDSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	100	-	-	V
1	Zero Gate Voltage Drain Current	$V_{DS} = 80V, V_{GS} = 0V$	-	-	1	uА
DSS	Zero Gale Voltage Drain Current	$T_{\rm J} = 150^{\rm o}{\rm C}$	-	-	250	μΑ
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	2	3	4	V
		I _D = 44A, V _{GS} = 10V	-	0.024	0.028	Ω
r _{DS(on)}	Drain to Source On Resistance	I _D = 21A, V _{GS} = 6V,	-	0.028	0.047	Ω
		$I_D = 44A, V_{GS} = 10V, T_J = 175^{\circ}C$	-	0.063	0.074	Ω

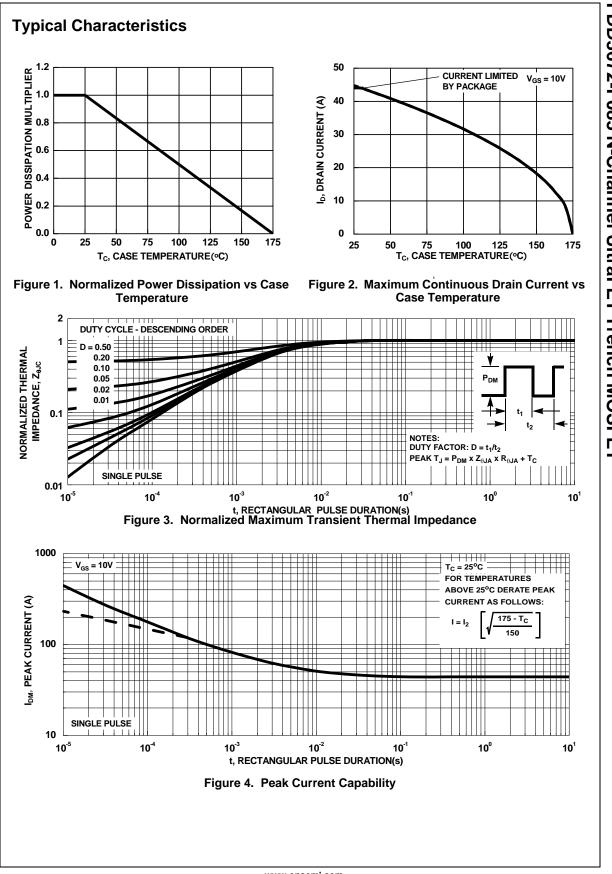
Dynamic Characteristics

C _{iss}	Input Capacitance		0)/	-	1635	-	pF
C _{oss}	Output Capacitance	−V _{DS} = 25V, V _{GS} = −f = 1MHz	υν,	-	240	-	pF
C _{rss}	Reverse Transfer Capacitance	1 = 1101112		-	60	-	pF
Q _{g(TOT)}	Total Gate Charge at 10V	$V_{GS} = 0$ to 10V		-	24	36	nC
Q _{g(TH)}	Threshold Gate Charge	$V_{GS} = 0$ to 2V	V _{DD} = 50V	-	3	4.5	nC
Q _{gs}	Gate to Source Gate Charge		I _D = 44A	-	8.3	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau		$I_g = 1.0 \text{mA}$	-	5.3	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	5.8	-	nC

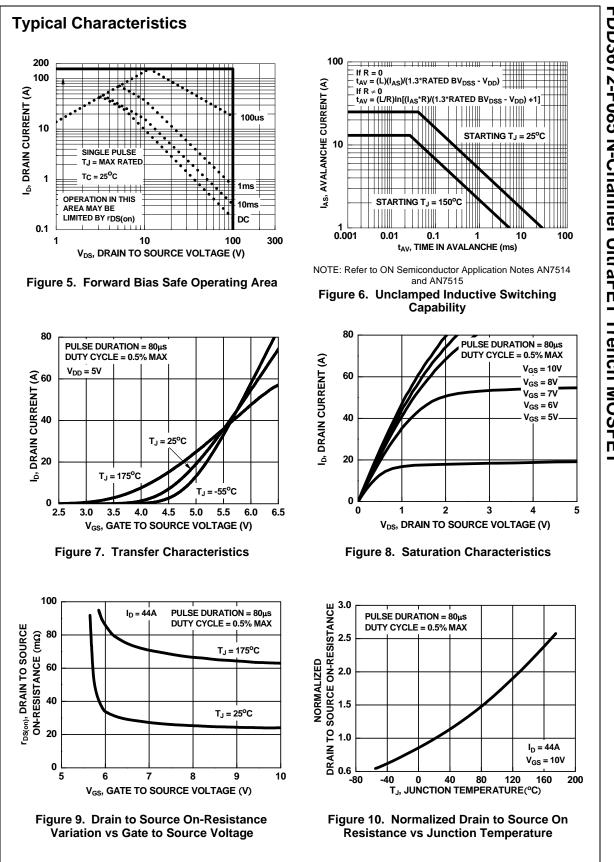
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switch	ing Characteristics					
t _{on}	Turn-On Time		-	-	78	ns
t _{d(on)}	Turn-On Delay Time	V _{DD} = 50V, I _D = 44A, V _{GS} = 10V, R _{GS} = 11Ω	-	12	-	ns
t _r	Turn-On Rise Time		-	37	-	ns
t _{d(off)}	Turn-Off Delay Time		-	24	-	ns
f	Turn-Off Fall Time		-	44	-	ns
t _{off}	Turn-Off Time		-	-	70	ns
t _f t _{off}					- 70	
V	Source to Drain Diode Voltage	I _{SD} = 44A	-	0.9	1.25	V
V _{SD}	Source to Drain Diode Voltage	I _{SD} = 21A	-	0.8	1.0	V
t _{rr}	Reverse Recovery Time	-440 d /dt - 1000//	-	44	57	ns
Q _{rr}	Reverse Recovery Charge	$I_{F} = 44A, dI_{SD}/dt = 100A/\mu s$	-	58	76	nC

Notes:

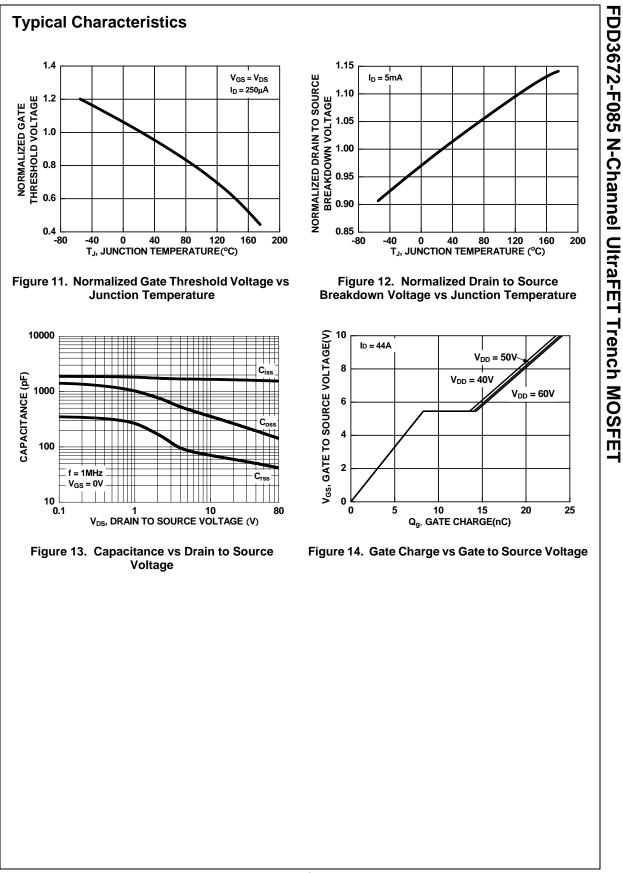
1: Starting $T_J = 25^{\circ}C$, L = 0.2mH, $I_{AS} = 27A$



FDD3672-F085 N-Channel UltraFET Trench MOSFET



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